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|  | <h2>SI1405BDH-T1-GE3</h2>  |
|   | <p><b>Hersteller-Teilenummer:</b> <a href="#">SI1405BDH-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 8V 1.6A SC-70-6</p> <p><b>Datenblätter:</b>  <a href="#">SI1405BDH-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 17585 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation.<br/>See specs for product details.</p>            |  |

### Spezifikationen

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|--|---|
| Teilenummer                                      | <a href="#">SI1405BDH-T1-GE3</a>                                    |
| Hersteller                                       | <a href="#">Electro-Films (EFI) / Vishay</a>                        |
| Beschreibung                                     | MOSFET P-CH 8V 1.6A SC-70-6   |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                       | 17585 pcs Stock   |
| detaillierte Beschreibung                        | P-Channel 8V 1.6A (Tc) 1.47W (Ta), 2.27W (Tc)                       |
| Serie  | TrenchFET®  |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | 6-TSSOP, SC-88, SOT-363   |
| Supplier Device-Gehäuse                          | SC-70-6 (SOT-363)   |
| Verlustleistung (max)                            | 1.47W (Ta), 2.27W (Tc)  |
| Typ FET  | P-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 8V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 1.6A (Tc)   |
| Rds On (Max) @ Id, Vgs                           | 112 mOhm @ 2.8A, 4.5V   |
| VGS (th) (Max) @ Id                              | 950mV @ 250µA   |
| Gate Charge (Qg) (Max) @ Vgs                     | 5.5nC @ 4.5V  |
| Eingabekapazität (Ciss) (Max) @ Vds              | 305pF @ 4V  |
| Antriebsspannung (Max Rds On, Min Rds On)        | 1.8V, 4.5V  |
| Vgs (Max)  | ±8V   |
| Verpackung                                       | Cut Tape (CT)   |
| Bleifreier Status / RoHS-Status                  | Lead free / RoHS Compliant  |
| Feuchtigkeitsempfindlichkeitsniveau (MSL)        | 1 (Unlimited)   |
| Andere Namen                                     | SI1405BDH-T1-GE3CT  |



















































SI1405BDH-T1-GE3 ist neu im Original. Suche SI1405BDH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1405BDH-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1405BDH-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|   |  |  |   |
|---|--|--|---|
|  <p><b>SI1405DL-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 8V 1.6A SC-70-6</p> |  <p><b>SI1405DL-T1</b><br/>VISHAY<br/>SI1405DL-T1 VISHAY</p>                                    |  <p><b>SI1404DL-T1-GE3</b><br/>V<br/>SI1404DL-T1-GE3 V</p>               |  <p><b>SI1405BDH-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 8V 1.6A SOT363</p> |
|  <p><b>SI1404DH-T1-GE3</b><br/>V<br/>SI1404DH-T1-GE3 V</p>                                     |  <p><b>SI1405DL-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 8V 1.6A SC-70-6</p> |  <p><b>SI1405BDH</b><br/>Vishay Precision Group<br/>SI1405BDH Vishay</p> |  <p><b>SI1405BDH-T1-GE3</b><br/>Vishay / Siliconix<br/>MOSFET P-CH 8V 1.6A SC-70-6</p>         |

### heiße Teile

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